# MOSFET - Single, P-Channel, Small Signal, XLLGA3, 0.62 x 0.62 x 0.4 mm -20 V, -223 mA

#### **Features**

- Single P-Channel MOSFET
- Ultra Small and Thin Package (0.62 x 0.62 x 0.4 mm)
- Low R<sub>DS(on)</sub> Solution in 0.62 x 0.62 mm Package
- 1.5 V Gate Voltage Rating
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

## **Applications**

- Small Signal Load Switch
- Analog Switch
- High Speed Interfacing
- Optimized for Power Management in Ultra Portable Products

### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise stated)

Parameter		Symbol	Value	Units	
Drain-to-Source Voltage		$V_{DSS}$	-20	V	
Gate-to-Source Voltage		V <sub>GS</sub>	±8.0	V	
Continuous Drain	Steady T <sub>A</sub> = 25°C	I <sub>D</sub>	-223	mA	
Current (Note 1)	State	T <sub>A</sub> = 85°C		-161	
	t ≤ 5 s	T <sub>A</sub> = 25°C		-240	
Power Dissipa- tion (Note 1)	Steady State	T <sub>A</sub> = 25°C	P <sub>D</sub>	121	mW
	t ≤ 5 s	T <sub>A</sub> = 25°C		140	
Pulsed Drain Current $t_p = 10 \mu s$		I <sub>DM</sub>	-669	mA	
Operating Junction and Storage Temperature			T <sub>J</sub> , T <sub>STG</sub>	-55 to 150	°C
Source Current (Body Diode)			I <sub>S</sub>	-121	mA
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			TL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Units
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	1035	°C/W
Junction-to-Ambient – t ≤ 5 s (Note 1)	$R_{\theta JA}$	895	

Surface Mounted on FR4 Board using the minimum recommended pad size, (or 2 mm<sup>2</sup>), 1 oz Cu.

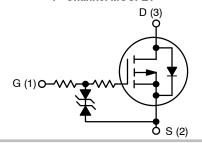


## ON Semiconductor®

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MOSFET					
V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> MAX	I <sub>D</sub> MAX			
	1.6 Ω @ -4.5 V				
-20 V	2.4 Ω @ -2.5 V	–223 mA			
-20 V	3.3 Ω @ –1.8 V	2201171			
	4.5 Ω @ -1.5 V				

#### P-Channel MOSFET



## MARKING DIAGRAM



XLLGA3 CASE 713AB



D = Specific Device Code

M = Date Code

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NTNS3A91PZT5G	XLLGA3 (Pb-Free)	8000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

2. Pulse Test: pulse width  $\leq 300~\mu\text{s},$  duty cycle  $\leq 2\%.$ 

# **ELECTRICAL CHARACTERISTICS** ( $T_J = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Test Condition		Min	Тур	Max	Units
OFF CHARACTERISTICS		•					_
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$		-20			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V <sub>(BR)DSS</sub> /T <sub>J</sub>	$I_D = -250 \mu A$ , ref to 25°C			11		mV/°C
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{GS} = 0 \text{ V},$ $V_{DS} = -20 \text{ V}$	T <sub>J</sub> = 25°C			-1.0	μΑ
Gate-to-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> = 0 V, \	/ <sub>GS</sub> = ±8.0 V			±2.0	μΑ
ON CHARACTERISTICS (Note 3)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	$V_{GS} = V_{DS}$ ,	I <sub>D</sub> = -250 μA	-0.4		-1.0	V
Negative Threshold Temperature Co- efficient	V <sub>GS(TH)</sub> /T <sub>J</sub>				2.1		mV/°C
Drain-to-Source On Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = -4.5 V <sub>3</sub>	I <sub>D</sub> = -100 mA		1.1	1.6	Ω
		$V_{GS} = -2.5 \text{ V}, I_D = -50 \text{ mA}$			1.5	2.4	
		V <sub>GS</sub> = -1.8 V	∕, I <sub>D</sub> = −20 mA		2.0	3.3	
		V <sub>GS</sub> = −1.5 V	/, I <sub>D</sub> = −10 mA		2.5	4.5	
Forward Transconductance	9FS	$V_{DS} = -5 \text{ V}, I_D = -100 \text{ mA}$			0.41		S
Source-Drain Diode Voltage	$V_{SD}$	$V_{GS} = 0 \text{ V}, I_{S} = -10 \text{ mA}$			-0.6	-1.0	V
CHARGES & CAPACITANCES							
Input Capacitance	C <sub>ISS</sub>				41		pF
Output Capacitance	C <sub>OSS</sub>	$V_{GS} = 0 V$ , $V_{DS} = 0 V$	$V_{GS} = 0 \text{ V, f} = 10 \text{ kHz,}$ $V_{DS} = -15 \text{ V}$		4.6		
Reverse Transfer Capacitance	C <sub>RSS</sub>	- 103			4.1		
Total Gate Charge	Q <sub>G(TOT)</sub>				1.1		nC
Threshold Gate Charge	Q <sub>G(TH)</sub>	V <sub>GS</sub> = -4.5 V,	$V_{GS} = -4.5 \text{ V}, V_{DS} = -15 \text{ V},$		0.1		
Gate-to-Source Charge	Q <sub>GS</sub>	$I_D = -200 \text{ mA}$			0.2		
Gate-to-Drain Charge	$Q_{GD}$				0.23		
SWITCHING CHARACTERISTICS, VG	S = 4.5 V (Note 3)						
Turn-On Delay Time	t <sub>d(ON)</sub>				41		ns
Rise Time	t <sub>r</sub>	$V_{GS}$ = -4.5 V, $V_{DD}$ = -15 V, $I_{D}$ = -200 mA, $R_{G}$ = 2 $\Omega$			97		
Turn-Off Delay Time	t <sub>d(OFF)</sub>				571		
Fall Time	t <sub>f</sub>				286		

 $<sup>{\</sup>it 3. \ \, Switching \, characteristics \, are \, independent \, of \, operating \, junction \, temperatures.}$ 

#### **TYPICAL CHARACTERISTICS**

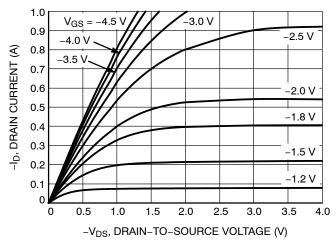


Figure 1. On-Region Characteristics

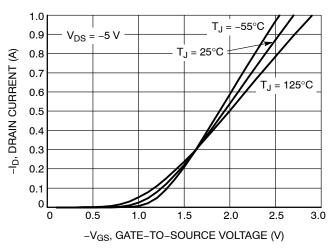


Figure 2. Transfer Characteristics

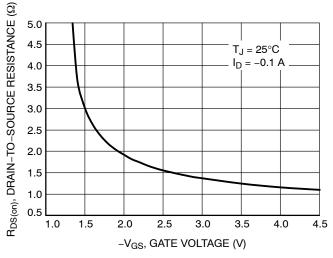


Figure 3. On-Resistance vs. Gate-to-Source Voltage

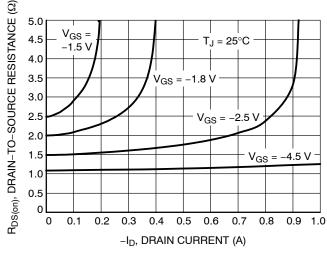


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

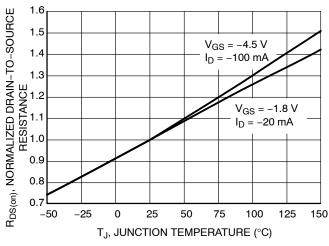


Figure 5. On Resistance Variation with Temperature

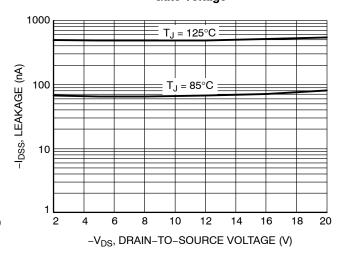
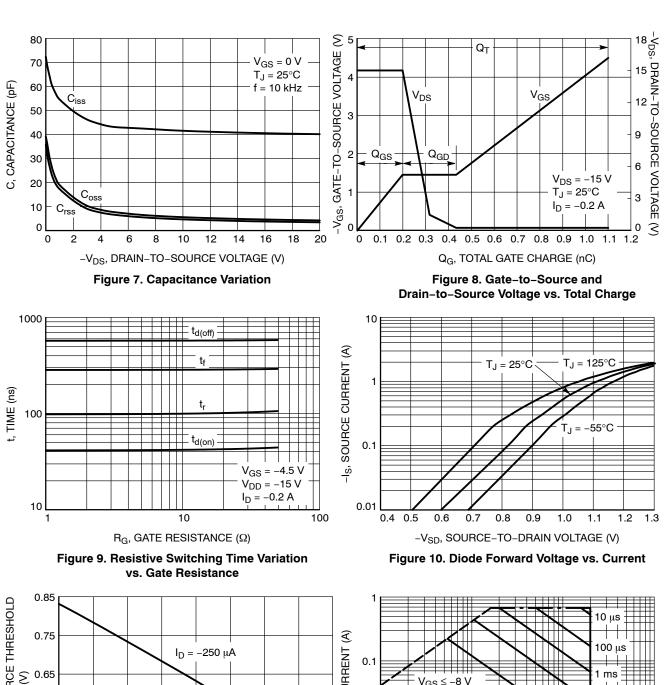


Figure 6. Drain-to-Source Leakage Current vs. Voltage

#### **TYPICAL CHARACTERISTICS**



-V<sub>GS(th)</sub>, GATE-TO-SOURCE THRESHOLD -ID, DRAIN CURRENT (A) VOLTAGE (V)  $V_{GS} \le -8 \text{ V}$ Single Pulse 10 ms  $T_C = 25^{\circ}C$ 0.55 0.01 R<sub>DS(on)</sub> Limit dc 0.45 Thermal Limit Package Limit 0.35 0.001 -50 -25 25 50 100 125 150 0.1 100

T<sub>J</sub>, TEMPERATURE JUNCTION (°C) Figure 11. Threshold Voltage

-V<sub>DS</sub>, DRAIN-TO-SOURCE VOLTAGE (V)

Figure 12. Maximum Rated Forward Biased
Safe Operating Area

### **TYPICAL CHARACTERISTICS**

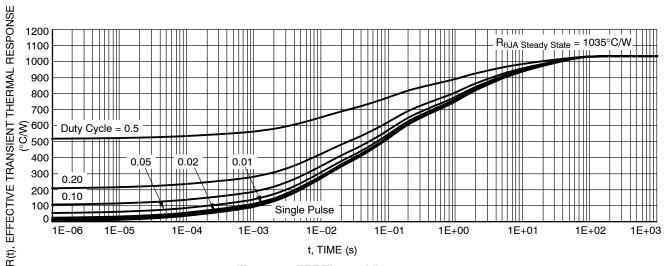
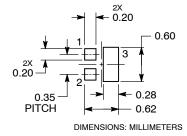


Figure 13. FET Thermal Response

# MINIMUM RECOMMENDED SOLDER FOOTPRINT\*

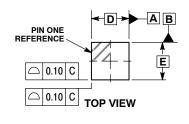


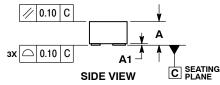
<sup>\*</sup>Dependent upon end user capabilities, this footprint could be used as a minimum.

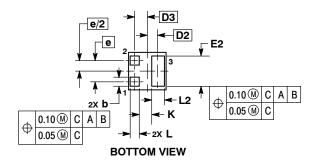


#### XLLGA3, 0.62x0.62, 0.35P CASE 713AB ISSUE O

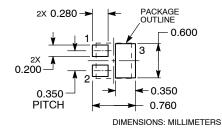
**DATE 25 SEP 2012** 







# RECOMMENDED SOLDER FOOTPRINT\*



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### NOTES:

- DIMENSIONING AND TOLERANCING PER
  ASME Y14 5M 1994
- ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.340	0.440	
A1	0.000	0.030	
b	0.100	0.200	
D	0.620	BSC	
D2	0.175 BSC		
D3	0.205 BSC		
E	0.620	BSC	
E2	0.400 0.600		
е	0.350 BSC		
K	0.200 REF		
L	0.090	0.210	
L2	0.110	0.310	

# GENERIC MARKING DIAGRAM\*



X = Specific Device Code

M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present.

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ſ	DESCRIPTION:	XLLGA3, 0.62X0.62, 0.35P		PAGE 1 OF 1	

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